

2020-11-09

Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser

Application	
Spectroscopy	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T _C	°C	0		20
Forward Current	I _F	mA			160
Reverse Voltage	V _R	V			0
Output Power (extracavity)	P _{opt}	mW			30

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C			20
Forward Current	I _F	mA			160

Characteristics at T_C= at 20°C, BOL under recommended working condition, with external cavity

Symbol	Unit	min	typ	max
λ_{C}	nm		655	
$\Delta\lambda_{tun}$	nm	650		660
P _{opt}	mW		20	
			TE	
			TEM00	
	λ_{C} $\Delta\lambda_{tun}$	$\lambda_{\rm C}$ nm $\Delta\lambda_{\rm tun}$ nm	$λ_{c}$ nm Δ $λ_{tun}$ nm 650	$λ_c$ nm655 $Δλ_{tun}$ nm650 P_{opt} mW20TE

Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Measurement Conditions / Comments

Measurement Conditions / Comments The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane Fundamental Mode

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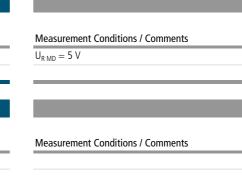
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without external cavity					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{ASE}	µA/mW	1		40
Chin Parameter					
Chip Parameter					
	Symbol	Unit	min	typ	max
Chip Parameter Parameter Cavity Length	Symbol L	Unit µm	min	typ 2000	max



Ordering Information: 800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093 Email orders to: sales@xsoptix.com Fax orders to: 800-878-7282

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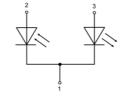
GAIN CHIPS AR coated Fabry-Perot Laser

Package Dimensions					
Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	h	mm	3.50	3.65	3.70
Excentricity of Emission Center	R	mm			0.12
Pin Length	L _{PIN}	mm		14	

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

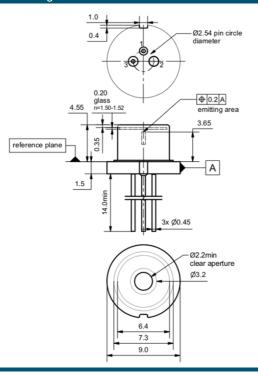
Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





Package Drawings





AIZ-16-0421-1517

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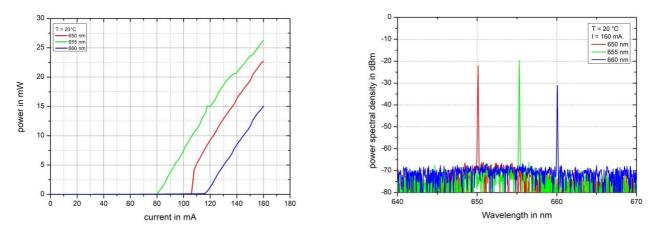


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Typical Measurement Results



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The TPA diode type is known to be sensitive against thermal stress. It should not be operated without appropriate injection from a seed laser. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode. The chip should be protected against moisture. A water vapor content below 5000 ppm is recommended for applications with high reliability requirements.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.



IEC-60825-0

VISIBLE LASER RADIATION AVOID FY OR SKIN EXPOSURE TO DIRECT OR SCATTERED RADIATION GaAS SEMICONDUCTOR LASER DIODE 30 mW MAX OUTPUT AT 555 m CLASS IV LASER PRODUCT

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